




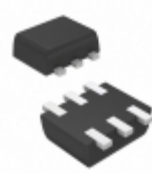




	DMG1013UWQ-7	
	Hersteller-Teilenummer:	DMG1013UWQ-7
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET P-CH 20V 0.82A SOT323
	Datenblätter:	 DMG1013UWQ-7.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 3000 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	DMG1013UWQ-7
Hersteller	Diodes Incorporated
Beschreibung	MOSFET P-CH 20V 0.82A SOT323
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	3000 pcs Stock
Serie	Automotive, AEC-Q101
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-70, SOT-323
Supplier Device-Gehäuse	SOT-323
Verlustleistung (max)	310mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	820mA (Ta)
Rds On (Max) @ Id, Vgs	750 mOhm @ 430mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.62nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	59.76pF @ 16V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±6V
Verpackung	Tape & Reel (TR)

























DMG1013UWQ-7 ist neu im Original, Suche DMG1013UWQ-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMG1013UWQ-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMG1013UWQ-7: Info@Y-IC.com

Sie können auch interessiert sein:

 DMG1016VQ-13 Diodes Incorporated MOSFET N/P-CH 20V SOT563	 DMG1013UWQ-13 Diodes Incorporated MOSFET PCH 20V 820MA SOT323	 DMG1016UDW-7 Diodes Incorporated MOSFET N/P-CH 20V SOT363	 DMG1016VQ-7 Diodes Incorporated MOSFET N/P-CH 20V SOT563
 DMG1013T-7-F DIODES DIODES SOT-523	 DMG1016V-7 Diodes Incorporated MOSFET N/P-CH 20V SOT563	 DMG1013T-7 Diodes Incorporated MOSFET P-CH 20V 0.46A SOT-523	 DMG1013UW-7 Diodes Incorporated MOSFET P-CH 20V 820MA SOT323

heiße Teile

Mehr

 DMG1012T	 DMG1012T-7	 DMG1012T-7-F	 DMG1012TQ-7	 DMG1012UW-7
 DMG1013T	 DMG1013T-7	 DMG1013TQ-7	 DMG1013UW-7	 DMG1016UDW-7
 DMG1016V	 DMG1016V-7	 DMG1023UV	 DMG1023UV-7	 DMG1024UV
 DMG1024UV-7	 DMG1026UV-7	 DMG1029SV-7	 DMG1029SV-7	 DMG204B10R
 DMG2301L-7	 DMG2301LK	 DMG2301LK-7	 DMG2301U	 DMG2301U-7
 DMG2301U-7-F	 DMG2302U	 DMG2302U-7	 DMG2302U-7-F	 DMG2302UK
 DMG2302UK-7	 DMG2302UQ	 DMG2302UQ-7	 DMG2305UX	 DMG2305UX-13
 DMG2305UX-7	 DMG2305UXQ	 DMG2305UXQ-7	 DMG2307L	 DMG2307L-7
 DMG2307L-7-F	 DMG264H00R	 DMG301NU-13	 DMG301NU-7	 DMG302PU-7
 DMG302PU-7	 DMG3401LSN	 DMG3401LSN-7	 DMG3401LSN-7-F	 DMG3402L-7

Contact us:Info@Y-IC.com

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